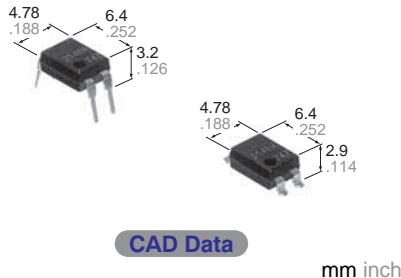


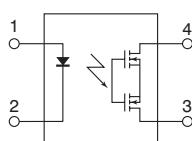
**High cost-performance
DIP4-pin type with
reinforced insulation**

**PhotoMOS Relays
GU-E 1 Form A
(AQY21OEH)**



CAD Data

mm inch



FEATURES

1. Reinforced insulation of 5,000 V

More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

2. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

3. High sensitivity and low on-resistance

Can control max. 0.13 A load current with 5 mA input current.

Low on-resistance of typ. 25Ω (AQY211EH).

4. Low-level off state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Security equipment
- Sensing equipment

TYPES

I/O isolation voltage	Output rating*	Output rating*		Package	Part No.		Packing quantity	
					Through hole terminal			
		Load voltage	Load current		Tube packing style		Tape and reel packing style	Tube
AC/DC dual use	Reinforced 5,000 V	30 V	1,000 mA	DIP4-pin	AQY211EH	AQY211EHA	AQY211EHAX	AQY211EHAZ
		60 V	550 mA		AQY212EH	AQY212EHA	AQY212EHAX	AQY212EHAZ
		350 V	130 mA		AQY210EH	AQY210EHA	AQY210EHAX	AQY210EHAZ
		400 V	120 mA		AQY214EH	AQY214EHA	AQY214EHAX	AQY214EHAZ
		600 V	50 mA		AQY216EH	AQY216EHA	AQY216EHAX	AQY216EHAZ

*Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay. (Ex. the label for product number AQY211EHAX is 211EH)

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

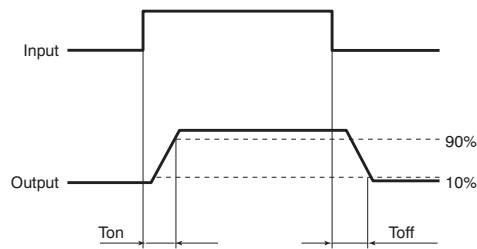
Item	Symbol	AQY211EH(A)	AQY212EH(A)	AQY210EH(A)	AQY214EH(A)	AQY216EH(A)	Remarks
Input	LED forward current	I _F		50mA			
	LED reverse voltage	V _R		5 V			
	Peak forward current	I _{FP}		1 A			f =100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}		75mW			
Output	Load voltage (peak AC)	V _L	30 V	60 V	350 V	400 V	600 V
	Continuous load current	I _L	1 A	0.55 A	0.13 A	0.12 A	0.05 A
	Peak load current	I _{peak}	3 A	1.5 A	0.4 A	0.3 A	0.15 A
	Power dissipation	P _{out}		500mW			
Total power dissipation	P _T			550mW			
I/O isolation voltage	V _{iso}			5,000 V AC			
Temperature limits	Operating	T _{opr}		-40°C to +85°C -40°F to +185°F			
	Storage	T _{stg}		-40°C to +100°C -40°F to +212°F			
				Non-condensing at low temperatures			

GU-E 1 Form A (AQY21OEH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY211EH(A)	AQY212EH(A)	AQY210EH(A)	AQY214EH(A)	AQY216EH(A)	Condition
Input	LED operate current	Typical	I_{Fon}	1.2mA		3.0mA		$I_L=Max.$
		Maximum		0.4mA		1.1mA		
	LED turn off current	Minimum	I_{Foff}	1.25 (1.14 V at $I_F=5mA$)		1.5V		$I_L=Max.$
		Typical		0.25Ω		0.85Ω	18Ω	
Output	On resistance	Typical	R_{on}	0.5Ω	2.5Ω	25Ω	35Ω	$I_F=5mA$ $I_L=Max.$ Within 1 s on time
		Maximum		0.25Ω		0.85Ω	18Ω	
	Off state leakage current	Maximum	I_{Leak}	1μA				$I_F=0mA$ $V_L=Max.$
Transfer characteristics	Turn on time*	Typical	T_{on}	1.5ms	1ms	0.5ms		$I_F=5mA$ $I_L=Max.$
		Maximum		5ms	4ms	2.0ms		
	Turn off time*	Typical	T_{off}	0.1ms	0.05ms	0.08ms	0.04ms	$I_F=5mA$ $I_L=Max.$
		Maximum		0.1ms		1.0ms		
	I/O capacitance	Typical	C_{iso}	0.8pF				$f = 1MHz$ $V_B = 0V$
		Maximum		1.5pF				
Initial I/O isolation resistance		Minimum	R_{iso}	1,000MΩ				500V DC

*Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I_F	5 to 10	mA

Dimensions

Schematic and Wiring Diagrams

Cautions for Use

These products are not designed for automotive use.

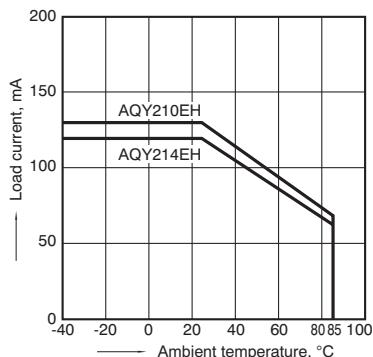
If you are considering to use these products for automotive applications, please contact your local Panasonic Electric Works technical representative.

Please refer to our information on [PhotoMOS Relays for Automotive Applications](#).

REFERENCE DATA

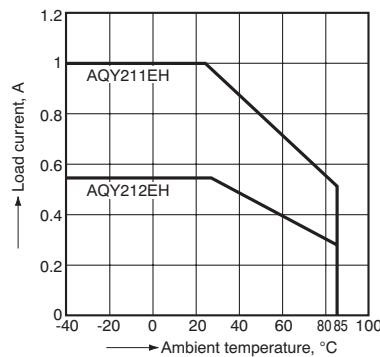
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



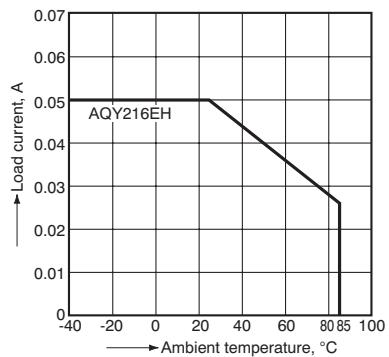
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



1-(3). Load current vs. ambient temperature characteristics

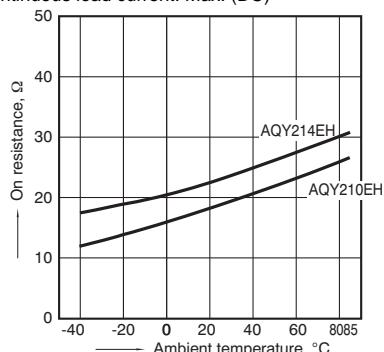
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



GU-E 1 Form A (AQY21OEH)

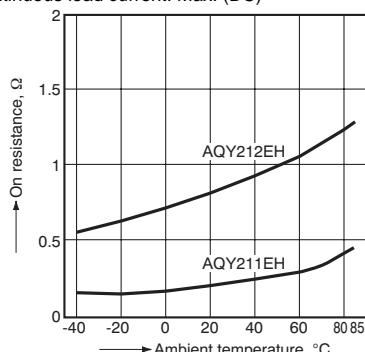
2-(1). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



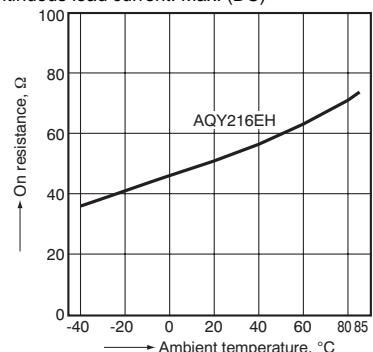
2-(2). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



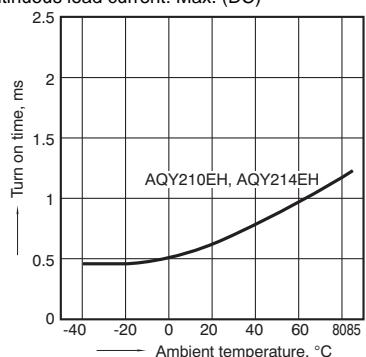
2-(3). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



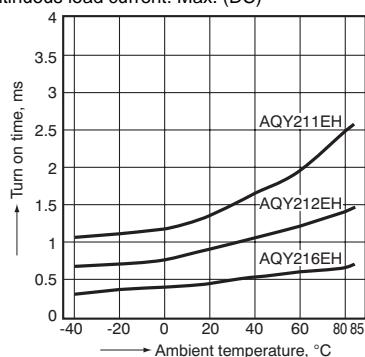
3-(1). Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



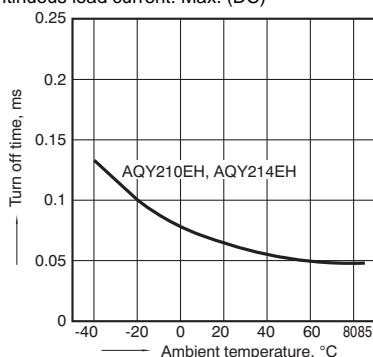
3-(2). Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



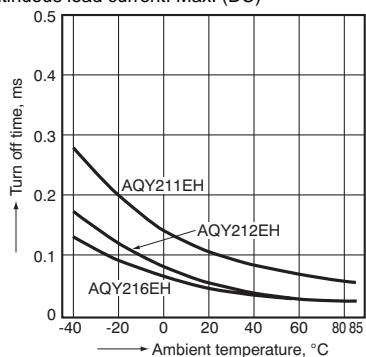
4-(1). Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



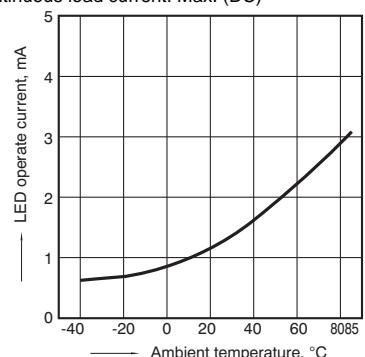
4-(2). Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



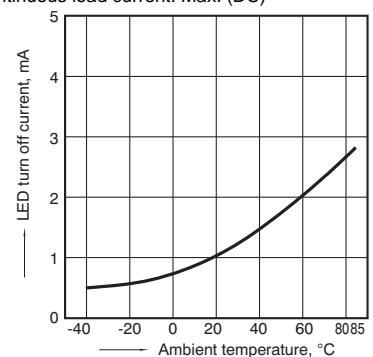
5. LED operate current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



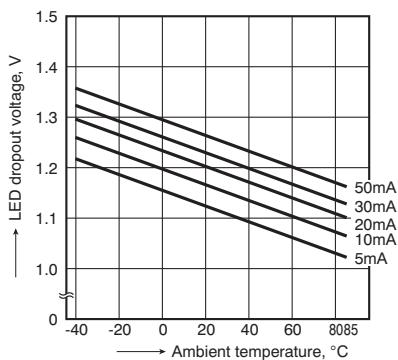
6. LED turn off current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



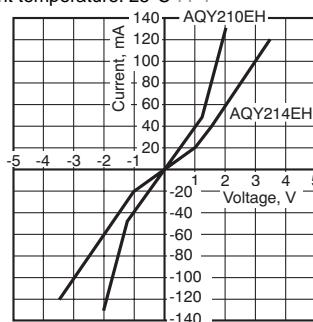
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types; LED current: 5 to 50 mA



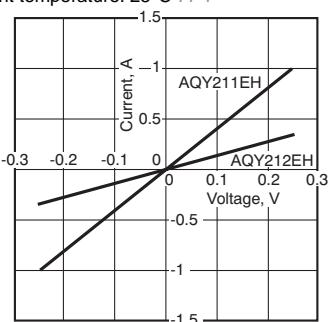
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F

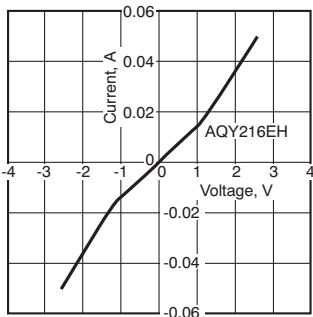


GU-E 1 Form A (AQY21OEH)

8-(3). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;

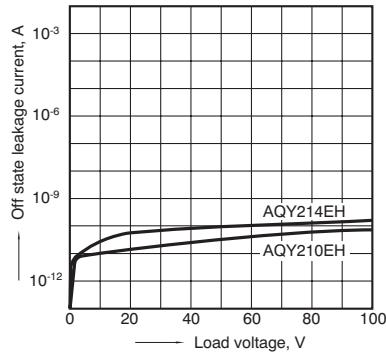
Ambient temperature: 25°C 77°F



9-(1). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4;

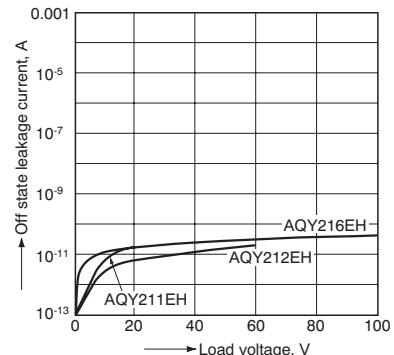
Ambient temperature: 25°C 77°F



9-(2). Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4;

Ambient temperature: 25°C 77°F

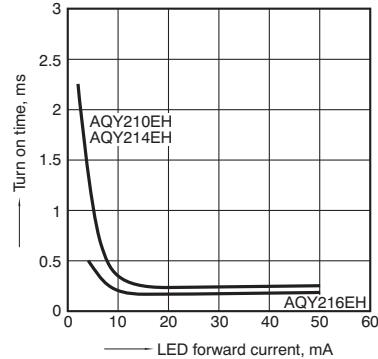


10-(1). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;

Load voltage: Max. (DC); Continuous load current:

Max. (DC); Ambient temperature: 25°C 77°F

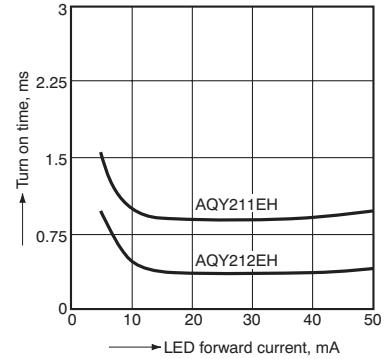


10-(2). Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;

Load voltage: Max. (DC); Continuous load current:

Max. (DC); Ambient temperature: 25°C 77°F

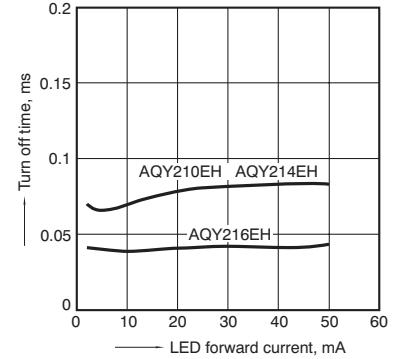


11-(1). Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;

Load voltage: Max. (DC); Continuous load current:

Max. (DC); Ambient temperature: 25°C 77°F

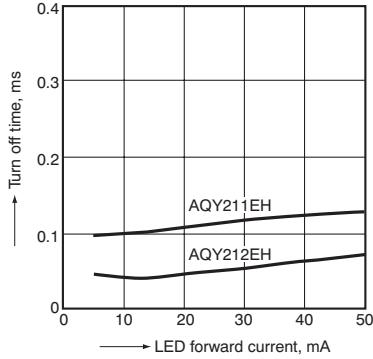


11-(2). Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;

Load voltage: Max. (DC); Continuous load current:

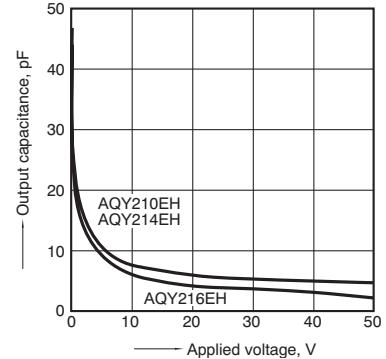
Max. (DC); Ambient temperature: 25°C 77°F



12-(1). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;

Frequency: 1 MHz; Ambient temperature: 25°C 77°F



12-(2). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;

Frequency: 1 MHz; Ambient temperature: 25°C 77°F

